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#### **Features**

- Optimized for Low-Voltage Core ICs in Portable Systems
- Very Small Package Dimension: WL-CSP 0.8 X 0.8 X 0.5 mm<sup>3</sup>
- Current = 1.2 A, V<sub>IN</sub> max. = 4 V
- Current = 2 A, V<sub>IN</sub> max. = 4 V (Pulsed)
- $R_{DS(ON)} = 80 \text{ m}\Omega \text{ at } V_{ON} = 0 \text{ V}, \text{ } V_{IN} = 4 \text{ V}$
- R<sub>DS(ON)</sub> = 85 mΩ at V<sub>ON</sub> = 0 V, V<sub>IN</sub> = 3.6 V
- $R_{DS(ON)} = 90 \text{ m}\Omega \text{ at } V_{ON} = 0 \text{ V}, \text{ } V_{IN} = 3 \text{ V}$
- RoHS Compliant

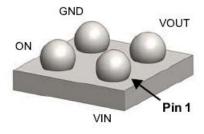


# **General Description**

This device is particularly suited for compact power management in portable applications where 1.6 V to 4 V input and 1.2 A output current capability are needed. This load switch integrates a level-shifting function that drives a P-channel power MOSFET in the very small 0.8 X 0.8 X 0.5 mm<sup>3</sup> WL-CSP package.

# Applications

- Load Switch
- Power Management in Portable Applications



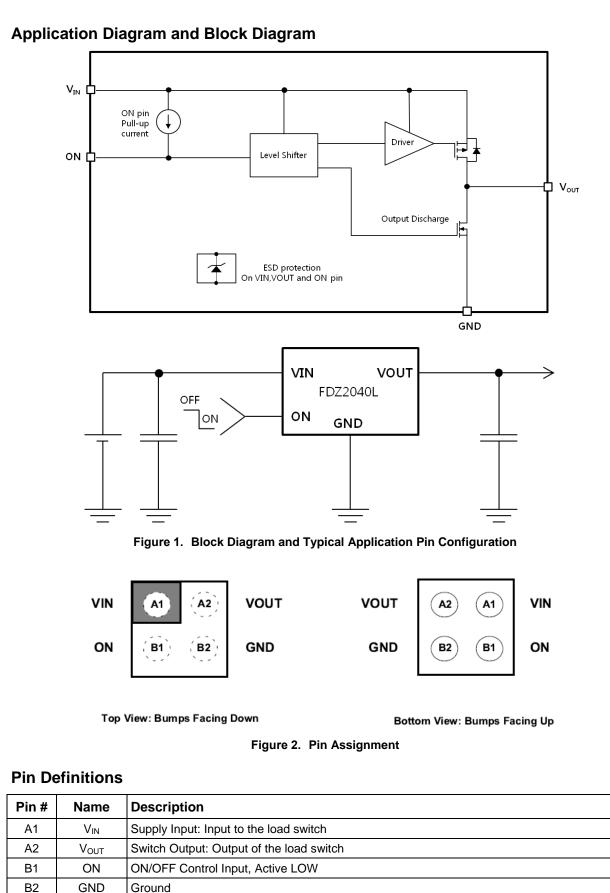
BOTTOM

Pin 1 Indicator

TOP

#### **Ordering Information**

Part Number	Device Marking	Ball Pitch	Operating Temperature Range	Switch	Package	Packing Method
FDZ2040L	ZL	0.4 mm	-25 to 75°C	80 mΩ, P-Channel MOSFET	0.8x0.8x0.5 mm <sup>3</sup> WL-CSP	Tape and Reel



# **Absolute Maximum Ratings**

Pa	Min.	Max.	Unit		
V <sub>IN</sub> , V <sub>OUT</sub> , ON to GND			4.2	V	
I <sub>out</sub> – Load Current (Continuous) <sup>(1a)</sup>		1.2	А		
I <sub>out</sub> – Load Current (Pulsed) <sup>(2)</sup>		2	А		
Power Dissipation @ $TA = 25^{\circ}C^{(1a)}$			0.9	W	
Operating Temperature Range	Operating Temperature Range				
Storage Temperature			150	°C	
Electrostatic Discharge Conshility	Human Body Model, JESD22-A114	8		L\ /	
Electrostatic Discharge Capability	Charged Device Model, JESD22-C101	2		- kV	

# **Thermal Characteristics**

Parameter	Min.	Max.	Unit
Thermal Resistance, Junction to Ambient <sup>(1a)</sup>		117	°C/W

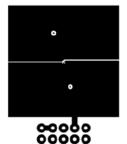
# **Recommended Operating Conditions**

Parameter	Min.	Max.	Unit
V <sub>IN</sub>	1.6	4.0	V
Ambient Operating Temperature, T <sub>A</sub>		75	°C

#### Notes:

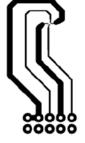
2.

 R<sub>θJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>θJC</sub> is guaranteed by design while R<sub>θJA</sub> is determined by the user's board design.



a. 117 °C/W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper.

Pulse Test: Pulse Width < 300  $\mu$ s, Duty Cycle < 2.0%.



 b. 277 °C/W when mounted on a minimum pad of 2 oz copper.

# **Electrical Characteristics**

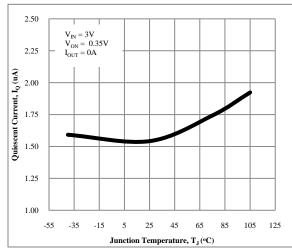
 $T_J$  = 25 °C unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V <sub>IN</sub>	Operation Voltage		1.6		4.0	V
VIL		$V_{IN}$ = 1.6 V, Ramp-Down V <sub>ON</sub> from 1 V to 0 V, V <sub>OUT</sub> LOW to HIGH, T <sub>J</sub> = -25 to 75°C			0.35	V
	ON Input Logic LOW Voltage	$V_{IN} = 4 V$ , Ramp-Down $V_{ON}$ from 1 V to 0 V, $V_{OUT}$ LOW to HIGH, $T_J = -25$ to 75°C			0.35	V
V <sub>IH</sub>		$V_{IN}$ = 1.6 V, Ramp-Up $V_{ON}$ from 0 V to 1 V, $V_{OUT}$ HIGH to LOW, $T_J$ = -25 to 75°C	1.35			V
	ON Input Logic HIGH Voltage	$V_{IN} = 4 \text{ V}$ , Ramp-Up $V_{ON}$ from 0 V to 1 V, $V_{OUT}$ HIGH to LOW, $T_J = -25$ to 75°C	1.35			V
Ιq	Quiescent Current			1.55	2.50	μA
I <sub>Q_off</sub>	Off Supply Current	$V_{IN} = 3 V, V_{ON} = 1.3 V, I_{OUT} = 0 A, T_J = -25 to 75^{\circ}C$		2.4	6.5	μA
I <sub>SD_off</sub>	Off Switch Current	$V_{IN} = 3 V, V_{ON} = 1.3 V, V_{OUT} = 0 V,$ T <sub>J</sub> = -25 to 75°C		0.1	3.5	μA
I <sub>Q off</sub>	Off Supply Current with ON	$V_{IN} = 3 V$ , $V_{ON} =$ Floating, $I_{OUT} = 0 A$		1.6	2.3	μA
(VON float)	Pin Floating	$V_{IN} = 3 \text{ V}, V_{ON} = \text{Floating}, I_{OUT} = 0 \text{ A}, T_J = -25 \text{ to } 75^{\circ}\text{C}$		1.6	4.0	μA
R <sub>PULL-DOWN</sub>	Output Pull-Down Resistance	V <sub>IN</sub> =3 V, I <sub>OUT</sub> =10 mA		22		Ω
	On Resistance	$V_{IN} = 1.6 V, V_{ON} = 0 V, I_{OUT} = 300 m A$		68	120	
R <sub>DS(ON)</sub>		$V_{IN} = 3 V, V_{ON} = 0 V, I_{OUT} = 300 m A$		50	90	
		$V_{IN} = 3.6 \text{ V}, V_{ON} = 0 \text{ V}, I_{OUT} = 300 \text{ mA}$		48	85	mΩ
		$V_{IN} = 4 V, V_{ON} = 0 V, I_{OUT} = 300 mA, T_J = -25 to 75^{\circ}C$		47	80	
C <sub>V-ON(INP)</sub>	ON Input Capacitance	T <sub>J</sub> = -25 to 75°C			5	pF
I <sub>ON(PULL-UP)</sub>	ON Pull-Up Current	$V_{\text{IN}}$ = 3 V, $V_{\text{ON}}$ = 0 V, $T_{\text{J}}$ = -25 to 75°C	0.30	0.76	1.20	μA

# **Switching Characteristics**

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
t <sub>on</sub>	Turn-On Time (V <sub>ON</sub> 50% to V <sub>OUT</sub> 90%)			45	150	ns
t <sub>don</sub>	Turn-On Delay (V <sub>ON</sub> 50% to V <sub>OUT</sub> 10%)			35	100	ns
t <sub>rise</sub>	Turn-On Rise Time (V <sub>OUT</sub> 10% to 90%)	$V_{IN}=3 V, V_{ON}=0 V$ as Logic LOW and		10	50	ns
t <sub>off</sub>	Turn-Off Time (V <sub>ON</sub> 50% to V <sub>OUT</sub> 10%)	1.3 V as Logic HIGH, $C_{OUT} = 1 \text{ nF}$ , $R_L = 30 \Omega$ , $T_J = -25 \text{ to } 75^{\circ}\text{C}$		60	150	ns
t <sub>doff</sub>	Turn-Off Delay (V <sub>ON</sub> 50% to V <sub>OUT</sub> 90%)			25	100	ns
t <sub>fall</sub>	Turn-Off Fall Time (V <sub>OUT</sub> 90% to 10%)			35	65	ns
$t_{don} - t_{doff}$	Turn-On Turn-Off Delay Delta				50	ns





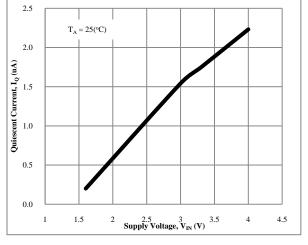


Figure 3. Quiescent Current vs. Temperature

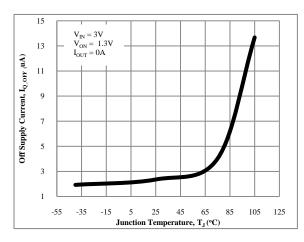
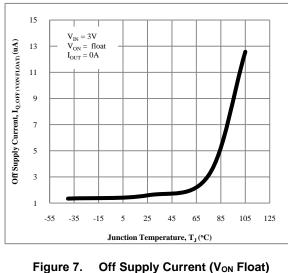


Figure 5.Off Supply Current vs. Temperature



vs. Temperature

Figure 4. Quiescent Current vs. Supply Voltage

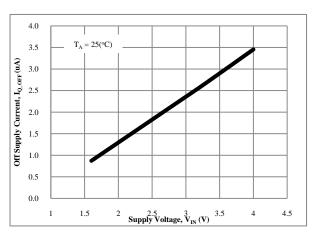
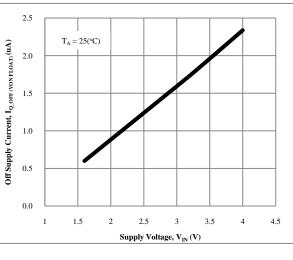
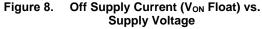
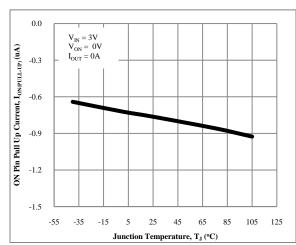


Figure 6. Off Supply Current vs. Supply Voltage

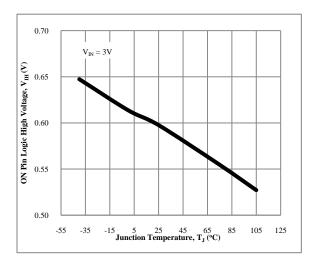




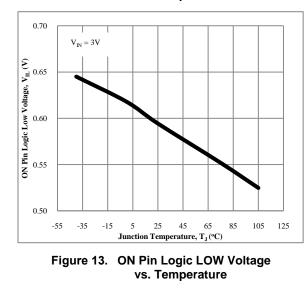












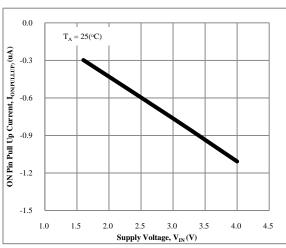


Figure 10. ON Pin Pull-Up Current vs. Supply Voltage

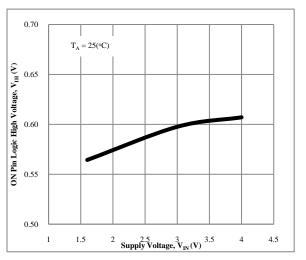
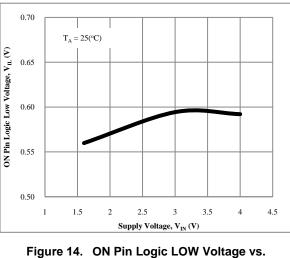
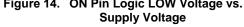


Figure 12. ON Pin Logic HIGH Voltage vs. Supply Voltage

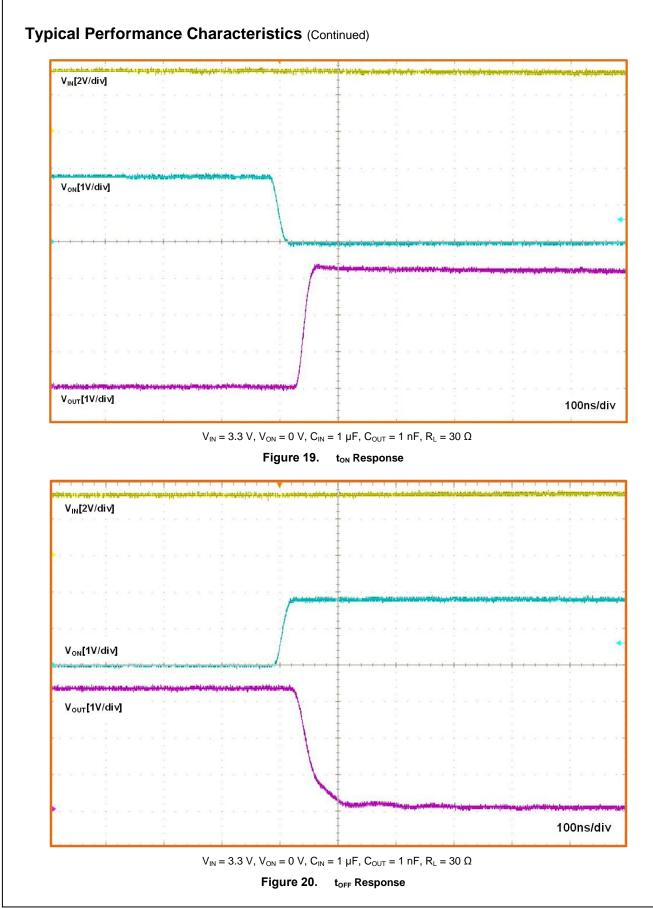




#### Typical Performance Characteristics (Continued) 35 35 $V_{IN} = 3V$ $T_A = 25(^{\circ}C)$ 30 30 Output Pull Down Resistance ( $\Omega$ ) Output Pull Down Resistance, $(\Omega)$ 25 25 20 20 15 15 10 10 -55 -35 -15 5 25 45 65 85 105 125 1.5 2 2.5 3 3.5 4 4.5 1 Supply Voltage, V<sub>IN</sub> (V) Junction Temperature, T<sub>1</sub> (°C) Figure 15. **Output Pull-Down Resistance** Figure 16. **Output Pull-Down Resistance vs.** vs. Temperature **Supply Voltage** 70 80 Static Drain to Source ON Resistance, $R_{\rm DSON}~(m\Omega)$ $\begin{array}{l} V_{IN}=3V\\ I_{OUT}=300mA \end{array}$ $T_A = 25(^{\circ}C)$ $I_{OUT} = 300mA$ (**Dm**) 75 65 70 Static Drain to Source ON Resistance, R<sub>DSON</sub> 60 65 60 55 55 50 50 45 45 40 40 35 35 30 30 1 1.5 2 2.5 3 3.5 4 4.5 -35 -55 -15 5 25 45 65 85 105 125 Supply Voltage, V<sub>IN</sub> (V) Junction Temperature, T<sub>J</sub>(°C)

Figure 17. Static Drain-to-Source ON Resistance vs. Temperature

Figure 18. Static Drain-to-Source ON Resistance vs. Supply Voltage

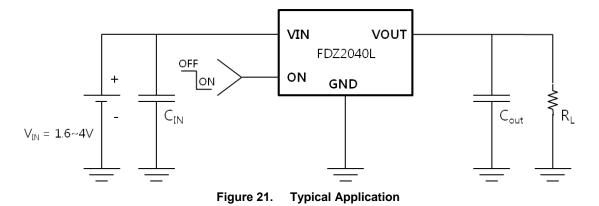


# **Operation Description**

The FDZ2040L is a low-R<sub>DS(ON)</sub> P-channel load switch packaged in space-saving 0.8 x 0.8 WL-CSP.

The core of the device is an  $80m\Omega$  P-channel MOSFET and capable of functioning over a wide input operating range of 1.6 V-4 V.

# **Applications Information**



#### **Input Capacitor**

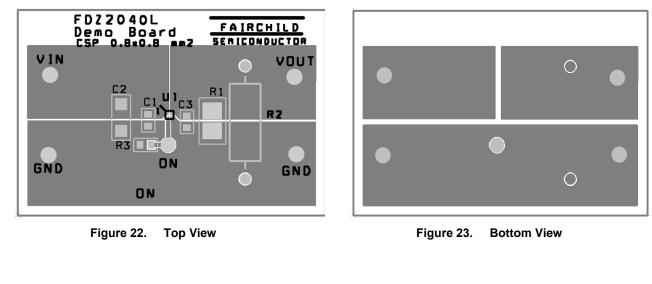
To reduce device inrush current effect, a 0.1  $\mu$ F ceramic capacitor, C<sub>IN</sub> is recommended close to the V<sub>IN</sub> pin. A higher value of C<sub>IN</sub> can be used to further reduce the voltage drop experienced as the switch is turned on into a large capacitive load.

#### **Output Capacitor**

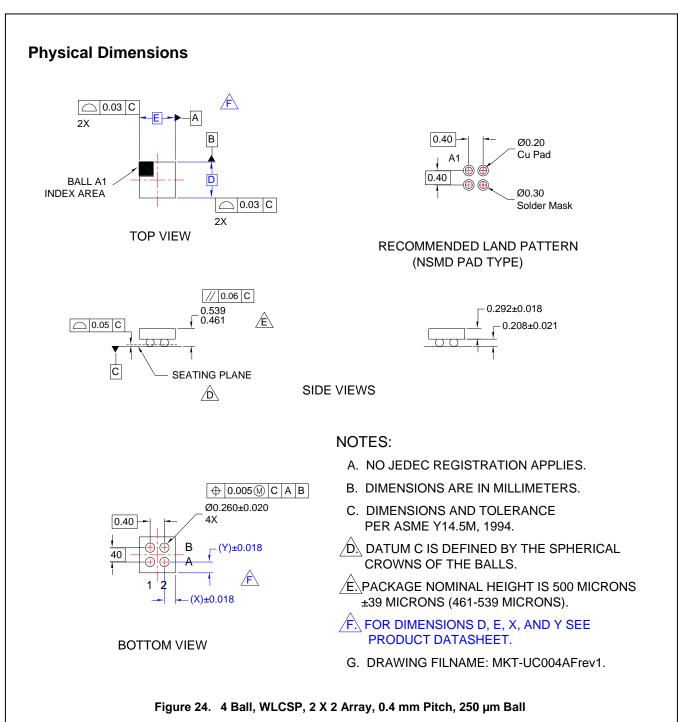
FDZ2040L switch works without an output capacitor. If parasitic board inductance forces  $V_{OUT}$  below GND when switching off, a 1 nF capacitor,  $C_{OUT}$ , should be placed between VOUT and GND.

#### Note:

3. The intrinsic diode for P-channel load switch would conduct if  $V_{OUT}$  is greater than  $V_{IN}$ , by a diode drop.



# **Evaluation Board Layout**



#### **Product-Specific Dimensions**

Product	D	E	Х	Y
FDZ2040L	0.8 ± 0.03 mm	0.8 ± 0.03 mm	0.21 mm	0.21 mm

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